WHAT IS CLAIMED IS:

A material comprising:

an amorphous material, wherein the amorphous material displays magnetic behavior; and

a dopant.

- 2. A material according to claim 1, wherein the amorphous material includes a nanoparticle.
- 3. A material according to claim 1, wherein said dopant comprises a dopant selected from n-type and p-type dopants.
- 4. A material according to claim 2, wherein said dopant comprises a dopant selected from n-type and p-type dopants.
- 5. A material according to claim 1, wherein said dopant comprises a dopant selected from transition metals, alkaline earth metals, alkali metals, and rare earth elements.
- 6. A material according to claim 2, wherein said dopant comprises a dopant selected from transition metals, alkaline earth metals, alkali metals, and rare earth elements.

- 7. A material according to claim 1, wherein said amorphous material has a defect density of at least 1×10^{20} defects/cm³.
- 8. A material according to claim 2, wherein said magnetic amorphous has a defect density of at least 1×10^{20} defects/cm³.
- 9. A material according to claim 1, wherein said amorphous material comprises silicon.
- 10. A material according to claim 2, wherein said amorphous material comprises silicon.
- 11. A material according to claim 10, wherein said nanoparticles comprise silicon.
- 12. A material according to claim 1, wherein said amorphous material comprises a material selected from III-V semiconductors or II-VI semiconductors.
- 13. A material according to claim 2, wherein said amorphous material comprises a material selected from III-V semiconductors or II-VI semiconductors.
- 14. A material according to claim 1, wherein said amorphous material comprises a metal.

- 15. A material according to claim 2, wherein said amorphous material comprises a metal.
- 16. A material according to claim 2, wherein said nanoparticles comprise a material selected from at least one of a Group III element and a Group V element.
- 17. A material according to claim 2, wherein said nanoparticles comprise a material selected from at least one of a Group II element and a Group V1 element.
 - 18. A material comprising:

a dopant.

an amorphous material, wherein said amorphous material comprises a ferromagnetic semiconductor; and

- 19. A material according to claim 18, wherein the amorphous material includes a nanoparticle.
- 20. A material according to claim 18, wherein said dopant comprises a dopant selected from n-type and p-type dopants.
- 21. A material according to claim 19, wherein said dopant comprises a dopant selected from n-type and p-type dopants.

- 22. A material according to claim 18, wherein said dopant comprises a dopant selected from transition metals, alkaline earth metals, alkali metals, and rare earth elements.
- 23. A material according to claim 19, wherein said dopant comprises a dopant selected from transition metals, alkaline earth metals, alkali metals, and rare earth elements.
- 24. A material according to claim 18, wherein said amorphous material has a defect density of at least 1×10^{20} defects/cm³.